

Enhanced ultrafast power diode

Rev.02 - 09 December 2024

Product data sheet

1. General description

Enhanced ultrafast power diode in a SOT404 (D2PAK) plastic package

2. Features and benefits

- High thermal cycling performance
- Low on-state losses
- Low thermal resistance
- Soft recovery characteristic
- Surface-mountable package

3. Applications

- Dual Mode (DCM and CCM) PFC
- Power Factor Correction (PFC) for Interleaved Topology

4. Quick reference data

l able 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _R	reverse voltage	DC	-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 126 °C; SQW; <u>Fig. 1</u> ; Fig. 2	-	-	5	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 µs; T _{mb} ≤ 126 °C; SQW	-	-	10	A
I _{FSM}	non-repetitive peak	t _p = 10 ms; T _{j(init)} = 25 °C; SIN; <u>Fig. 3</u>	-	-	60	А
	forward current	t _p = 8.3 ms; T _{j(init)} = 25 °C; SIN; <u>Fig. 3</u>	-	-	66	А
Static chara	acteristics	· · · · ·				
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.3	1.9	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.1	1.7	V
Dynamic ch	naracteristics	·				
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_i = 25 \text{ °C}; Fig. 6$	-	17.5	35	ns

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		
2	К	cathode		K — A 001aaa020
3	А	anode		
mb	К	mounting base; connected to cathod		

[1] it is not possible to make connection to Pin 2 of the TO263 package.

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYV25FB-600	TO263	BYV25FB-600,118	Reel	800	TO263N (N)	26-Sep-2016
					TO263P (P)	12-Jun-2023

7. Marking

Table 4. Marking codes						
Type number	Marking codes					
	Assembly factory: N	Assembly factory: P				
BYV25FB-600	BYV25FB 600 PJNxxxx xx	BYV25FB 600 PJPxxxx xx				

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8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 126 °C; SQW; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	5	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 µs; T _{mb} ≤ 126 °C; SQW	-	10	A
I _{FSM}	non-repetitive peak	t _p = 10 ms; T _{j(init)} = 25 °C; SIN; <u>Fig. 3</u>	-	60	А
	forward current	t _p = 8.3 ms; T _{j(init)} = 25 °C; SIN; <u>Fig. 3</u>	-	66	А
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

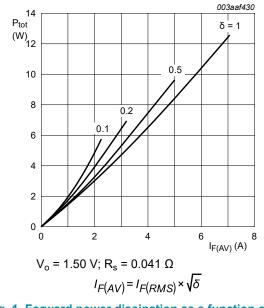


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

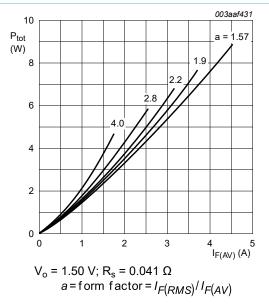
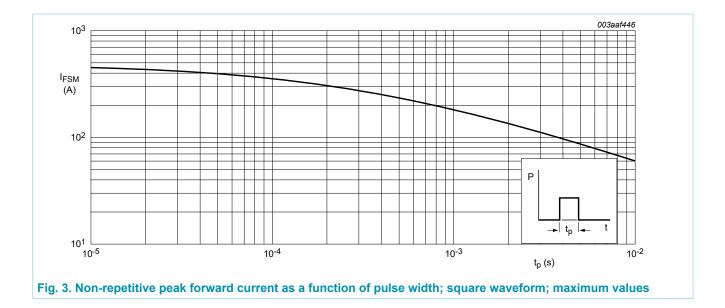


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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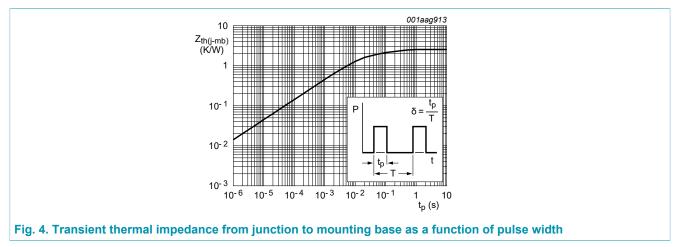
BYV25FB-600

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9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4		-	-	2.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	[1]	-	50	-	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

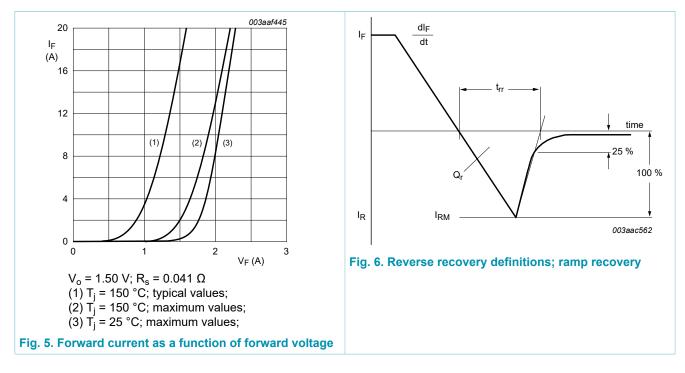


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10. Characteristics

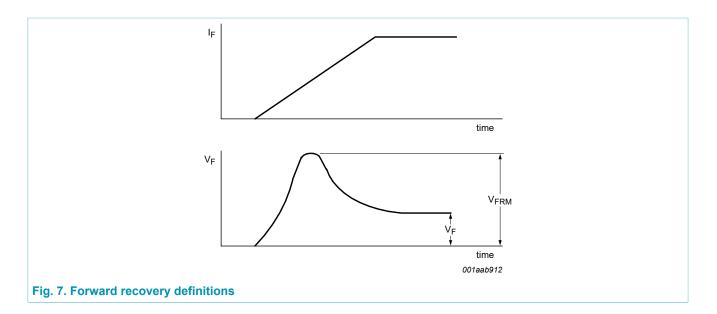
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.3	1.9	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.1	1.7	V
I _R	reverse current	V _R = 600 V; T _j = 100 °C	-	-	1.5	mA
		V _R = 600 V; T _j = 25 °C	-	-	50	μA
Dynamic ch	naracteristics			1		
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 6</u>	-	17.5	35	ns
I _{RM}	peak reverse recovery current	I_F = 1 A; V_R = 30 V; dI_F/dt = 100 A/µs; T_j = 25 °C	-	1.5	-	A
Q _r	recovered charge		-	13	-	nC
V _{FR}	forward recovery voltage	I _F = 1 A; dI _F /dt = 100 A/μs; T _j = 25 °C; Fig. 7	-	3.2	-	V



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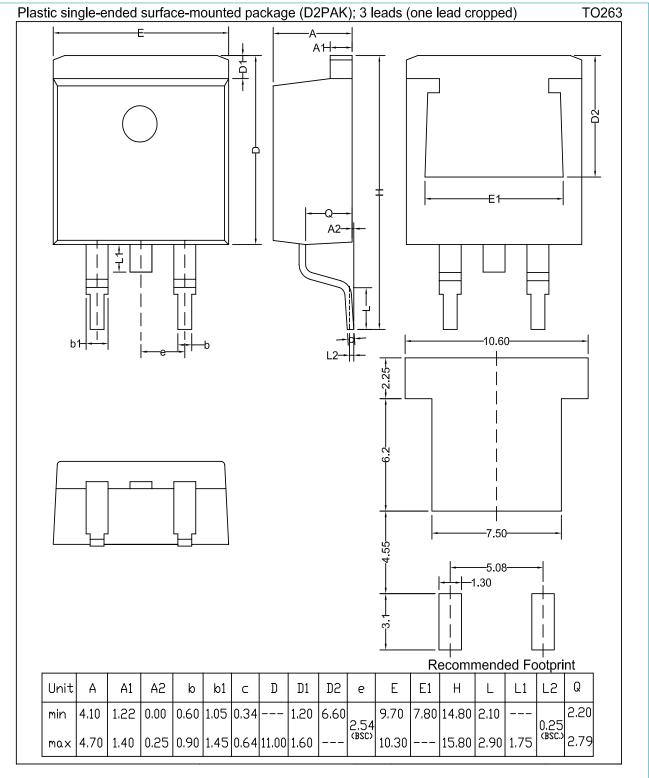
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BYV25FB-600

11. Package outline

Assembly factory: N



Assembly factory: P

Plastic single-en	nded sur	face-mo	ounted p	ackage (D2PAK); 3 leads (one lead cropped)	TO263
				$ \begin{array}{c} A \\ \hline \\$	
Dim A A1 A2 b b1 C C1 D D1 D2 E E1 e H L L1	All Din Min 4.30 0 2.50 0.70 1.10 0.40 1.17 9.10 1.00 7.40 9.80 7.60 14.80 2.10 1.30	nensions in M Typ 4.46 0.13 2.60 0.80 1.27 0.52 1.30 9.25 1.10 7.70 10.00 7.80 2.54 BSC 15.30 2.47 1.50	illimeters Max 4.60 0.25 2.70 0.90 1.45 0.60 1.40 9.40 1.30 8.00 10.20 8.00 15.80 2.80 1.70		

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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